DISCRETE SEMICONDUCTORS



Product specification Supersedes data of July 1986 File under Discrete Semiconductors, SC01 1996 Mar 13



Product specification

BAV45

FEATURES

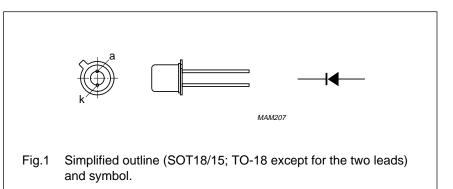
- Extremely low leakage current: max. 5 pA
- · Low diode capacitance
- Light insensitive.

APPLICATION

- Clamping
- Holding
- · Peak follower
- Time delay circuits
- Logarithmic amplifiers
- Protection of insulated gate field-effect transistors.

DESCRIPTION

Silicon diode in a metal TO-18 can. It has an extremely low leakage current over a wide temperature range combined with a low capacitance and is not sensitive to light.



CAUTION

Handle the device with care whilst soldering into the circuit. The extremely low leakage current can only be guaranteed when the bottom is free from solder flux or other contaminations.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage		_	35	V
V _R	continuous reverse voltage		_	20	V
IF	continuous forward current	see Fig.2	_	50	mA
I _{FRM}	repetitive peak forward current		_	100	mA
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	_	200	mW
T _{stg}	storage temperature		-65	+125	°C
Tj	junction temperature		_	125	°C

Note

1. Device mounted on a FR4 printed-circuit board.

Product specification

BAV45

ELECTRICAL CHARACTERISTICS

 $T_i = 25 \ ^{\circ}C$ unless otherwise specified.

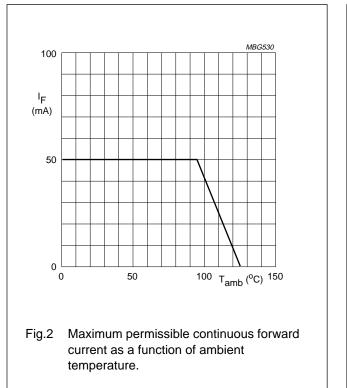
SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	$I_F = 10 \text{ mA}$; see Figs 3 and 3	1	V
I _R	reverse current	see Fig.5		
		$V_R = 5 V$	5	pА
		V _R = 5 V; T _j = 80 °C	250	pА
		V _R = 20 V	10	pА
C _d	diode capacitance	$f = 1 \text{ MHz}; V_R = 0; \text{ see Fig.6}$	1.3	pF
t _{rr}	reverse recovery time	when switched from $I_F = 10$ mA to $I_R = 10$ mA; R _L = 100 Ω ; measured at $I_R = 1$ mA; see Fig.7	600	ns

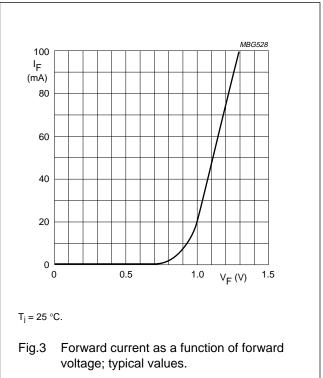
THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient; note 1		K/W

Note

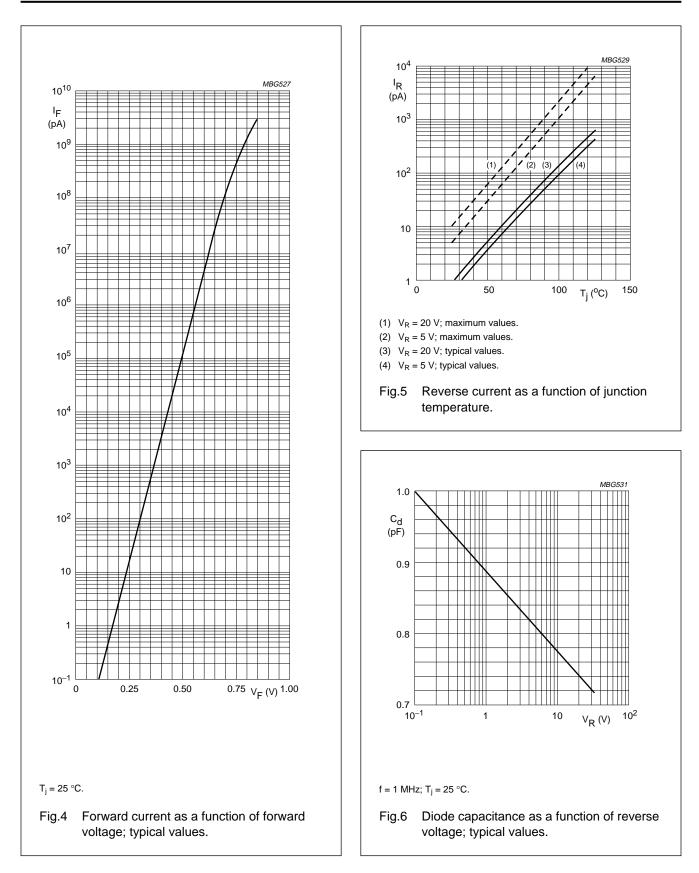
GRAPHICAL DATA



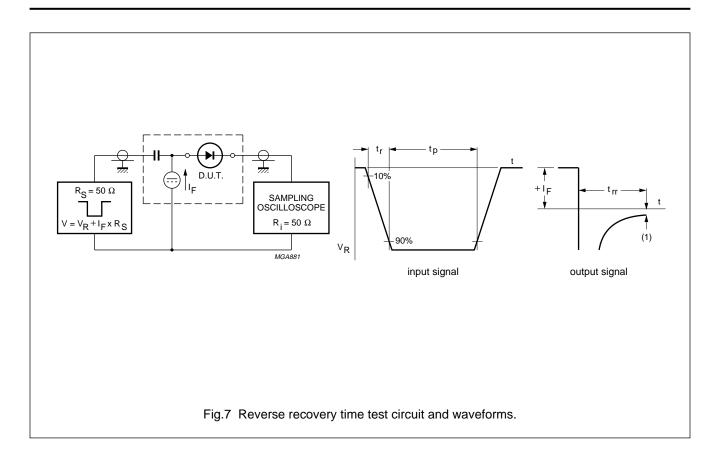


^{1.} Device mounted on a FR4 printed-circuit board.

BAV45

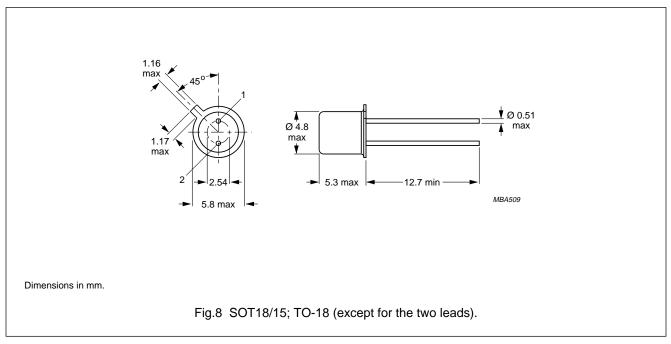


BAV45



BAV45

PACKAGE OUTLINE



DEFINITIONS

Data Sheet Status			
Objective specification	cification This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.		
Product specification	This data sheet contains final product specifications.		
Limiting values			
more of the limiting values i of the device at these or at	accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or may cause permanent damage to the device. These are stress ratings only and operation any other conditions above those given in the Characteristics sections of the specification limiting values for extended periods may affect device reliability.		
Application information			
Where application information is given, it is advisory and does not form part of the specification.			

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.